

an absorber disposed on said second contact and filling the interrupts in said second contact.

16. The thin film photovoltaic device of claim **15** wherein said absorber comprises a p-type semiconductor or a n-type conductor and said first semiconductor comprises the other of the p-type semiconductor and n-type conductor.

17. The thin film photovoltaic device of claim **15** comprising the limitations of a) or b):

a) wherein said absorber comprises a p-type semiconductor and said second semiconductor comprises the same or different p-type semiconductor; and

b) wherein said absorber comprises a n-type semiconductor and said second semiconductor comprises the same or different n-type semiconductor.

18. The back contact thin film photovoltaic device of claim **17** wherein said second semiconductor and said absorber comprise the same material.

19. The back contact thin film photovoltaic device of claim **15** wherein said second contact comprises a planar sheet interrupted with holes therein.

20. The back contact thin film photovoltaic device of claim **15** wherein said second contact comprises a plurality of interconnected wires interrupted with spacing between the interconnected wires.

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